

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP161G

TRIAC DRIVE

PROGRAMMABLE CONTROLLERS

AC-OUTPUT MODULE

SOLID STATE RELAY

The TOSHIBA MINI FLAT COUPLER TLP161G is a small outline coupler, suitable for surface mount assembly.

The TLP161G consists of a photo triac, optically coupled to a gallium arsenide infrared emitting diode.

- Zero-Voltage Crossing Turn-on
- Peak Off-State Voltage : 400V (MIN.)
- Trigger LED Current : 10mA (MAX.)
- On-State Current : 70mA (MAX.)
- Isolation Voltage : 2500Vrms (MIN.)
- UL Recognized : UL1577, File No. E67349

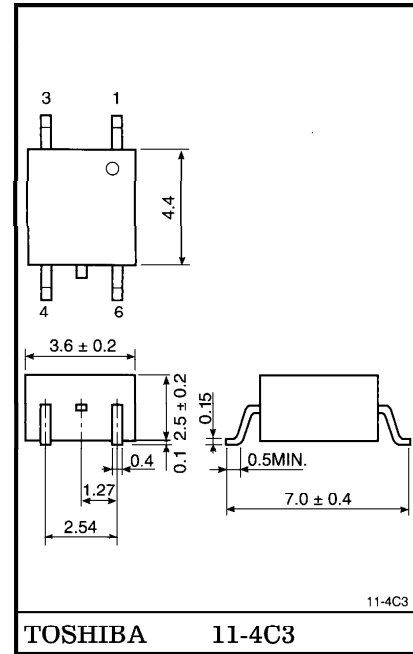
TRIGGER LED CURRENT

CLASSIFICATION*	TRIGGER LED CURRENT (mA)		MARKING OF CLASSIFICATION
	$V_T = 3V, T_a = 25^\circ C$		
	MIN.	MAX.	
(IFT5)	—	5	T5
(IFT7)	—	7	T5, T7
Standard	—	10	T5, T7, Blank

*Ex. (IFT5) ; TLP161G (IFT5)

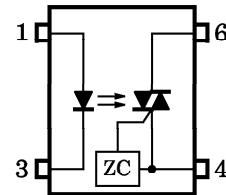
(Note) Application type name for certification test, please use standard product type name, i.e. TLP161G (IFT5) : TLP161G

Unit in mm



Weight : 0.09g

PIN CONFIGURATIONS



1. ANODE
3. CATHODE
4. TERMINAL 1
6. TERMINAL 2

961001EBC2

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● Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

● The products described in this document are subject to foreign exchange and foreign trade control laws.

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● The information contained herein is subject to change without notice.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta ≥ 53°C)	$\Delta I_F / ^\circ C$	-0.7	mA / °C
	Peak Forward Current (100µs pulse, 100pps)	I_{FP}	1	A
	Reverse Voltage	V_R	5	V
	Junction Temperature	T_j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V_{DRM}	400	V
	On-State RMS Current	Ta = 25°C	70	mA
		Ta = 70°C	40	
	On-State Current Derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ C$	-0.67	mA / °C
	Peak On-State Current (100µs pulse, 120pps)	I_{TP}	2	A
	Peak Nonrepetitive Surge Current (PW = 10ms, DC = 10%)	I_{TSM}	1.2	A
	Junction Temperature	T_j	115	°C
Storage Temperature Range	T_{stg}	-55~125	°C	
Operating Temperature Range	T_{opr}	-40~100	°C	
Lead Soldering Temperature (10s)	T_{sol}	260	°C	
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note)	BV_S	2500	Vrms	

(Note) Device considered a two terminal device : Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{AC}	—	—	120	Vac
Forward Current	I_F	15	20	25	mA
Peak On-State Current	I_{TP}	—	—	1	A
Operating Temperature	T_{opr}	-25	—	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Peak Off-State Current	I_{DRM}	$V_{DRM} = 400\text{V}$	—	10	1000	nA
	Peak On-State Voltage	V_{TM}	$I_{TM} = 70\text{mA}$	—	1.7	2.8	V
	Holding Current	I_H	—	—	0.6	—	mA
	Critical Rate of Rise of Off-State Voltage	dv/dt	$V_{in} = 120\text{Vrms}, T_a = 85^\circ\text{C}$ (Fig.1)	200	500	—	$\text{V}/\mu\text{s}$
	Critical Rate of Rise of Commutating Voltage	$dv/dt(c)$	$V_{in} = 30\text{Vrms}, I_T = 15\text{mA}$ (Fig.1)	—	0.2	—	$\text{V}/\mu\text{s}$

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$V_T = 3\text{V}$	—	5	10	mA
Inhibit Voltage	V_{IH}	$I_F = \text{Rated } I_{FT}$	—	—	40	V
Leakage in Inhibited State	I_{IH}	$I_F = \text{Rated } I_{FT}$ $V_T = \text{Rated } V_{DRM}$	—	100	300	μA
Capacitance (Input to Output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	Vrms
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

Fig.1 dv/dt TEST CIRCUIT

